



EL844055519

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. .... 09/292,132  
Filing Date .... April 14, 1999  
Inventor .... Salman Akram  
Assignee .... Micron Technology, Inc.  
Group Art Unit .... 2812  
Examiner .... S. Mulpuri  
Attorney's Docket No. .... MI22-1171  
Title: Methods of Forming a Transistor Gate

**RESPONSE TO OCTOBER 26, 2001 FINAL OFFICE ACTION**  
**TO ACCOMPANY RCE FILING**

To: Box RCE  
Assistant Commissioner for Patents  
Washington, D.C. 20231

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**AMENDMENTS**

**In the Claims**

Please replace the claims with the following clean version of the entire set of pending claims, in accordance with 37 C.F.R. § 1.121(c)(1)(i). Cancel all previous versions of any pending claim.

A marked up version showing amendments to any claims being changed is provided in one or more accompanying pages separate from this amendment in accordance with 37 C.F.R. § 1.121(c)(1)(ii). Any claim not accompanied by a marked up version has not been changed relative to the immediate prior version, except that marked up versions are not being supplied for any added claim or canceled claim.